NSN 5961-01-295-8533

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Inclosure Material:
Metal
Overall Length:
1.563 inches
Overall Height:
0.350 inches
Overall Width:
0.820 inches
End Application:
4920-01-187-4068 test system, automatic, radar
Mounting Facility Quantity:
2
Internal Configuration:
Field effect
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-204ae
Mounting Method:
Unthreaded hole
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 4.5 gate to source threshold voltage
Current Rating Per Characteristic:
35.00 amperes zero-gate-voltage drain current
Power Rating Per Characteristic:
150.0 watts total device dissipation
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Terminal Type And Quantity:
2 pin and 1 case
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0